

## [Product Information]

Ver.1.2

# IMX540-AAMJ

Diagonal 19.3 mm (Type 1.2) CMOS solid-state Image Sensor with Square Pixel for Monochrome Cameras

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### Description

The IMX540-AAMJ is a diagonal 19.3 mm (Type 1.2) CMOS active pixel type solid-state image sensor with a square pixel array and 24.55 M effective pixels. This chip features a global shutter with variable charge-integration time. This chip operates with analog 3.3 V, 2.9 V, digital 1.1 V, and interface 1.8 V quadruple power supply. High sensitivity and low dark current characteristics are achieved.

(Applications: FA cameras, ITS cameras)

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### Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Global shutter function
- ◆ Input frequency 37.125 MHz / 74.25 MHz / 54 MHz
- ◆ Number of recommended recording pixels: 5320 (H) × 4600 (V) approx. 24.47 M pixels
- ◆ Readout mode
  - All-pixel scan mode
  - Vertical / Horizontal 1/2 Subsampling mode
  - 2 × 2 FD binning mode
  - ROI mode
  - Vertical / Horizontal - Normal / Inverted readout mode
- ◆ Readout rate
  - Maximum frame rate in
  - All-pixel scan mode: 8 bit 35 frame/s, 10 bit 28 frame/s, 12 bit 24 frame/s
- ◆ Pulse Output Function
  - The monitor output for Exposure period
  - Programmable pulse output
- ◆ 8-bit / 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function
  - 0 dB to 24 dB: Analog Gain (0.1 dB step)
  - 24.1 dB to 48 dB: Analog Gain: 24 dB + Digital Gain: 0.1 dB to 24 dB (0.1 dB step)
- ◆ I/O interface
  - SLVS (2 ch / 4 ch / 8 ch switching) output (594 / 297 / 891 / 445.5 Mbps per ch)
  - SLVS - EC (1 Lane / 2 Lane) output (4.752 / 2.376 / 1.188 Gbps per Lane)
- ◆ Recommended lens F number: 2.8 or more (Close side)

### Pregius S

\* Pregius S is a registered trademark or trademark of Sony Group Corporation or its affiliates. Pregius S is a global shutter sensor technology for active pixel-type CMOS image sensors. By stacking the signal processing on the back illuminated type CMOS Image Sensor it realizes small chip size and high sensitivity, whilst using the high picture quality global shutter pixel technology of Pregius.

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**Device Structure**

◆ CMOS image sensor			
◆ Image size	Diagonal 19.3 mm (Type 1.2)	Approx. 24.55 M pixels	All-pixel
◆ Total number of pixels	5328 (H) × 4672 (V)	Approx. 24.89 M pixels	
◆ Number of effective pixels	5328 (H) × 4608 (V)	Approx. 24.55 M pixels	
◆ Number of active pixels	5328 (H) × 4608 (V)	Approx. 24.55 M pixels	
◆ Number of recommended recording pixels	5320 (H) × 4600 (V)	Approx. 24.47 M pixels	All-pixel
◆ Unit cell size	2.74 μm (H) × 2.74 μm (V)		
◆ Optical black	Horizontal (H) direction: Front 0 pixel, rear 0 pixel Vertical (V) direction: Front 64 pixels, rear 0 pixel		
◆ Package	230 pin LGA	21.0 mm (H) × 20.0 mm (V)	

**Image Sensor Characteristics**

(Tj = 60 °C)

Item		Value	Remarks
Sensitivity	Typ.	14510 Digit/lx/s	
Saturation signal	Min.	4094 Digit	

**Basic Drive Mode**

Drive mode	Recommended number of recording pixels	Maximum frame rate [frame/s]	Output interface	ADC [bit]
All pixel	5320 (H) × 4600 (V) approx. 24.47 M pixels	30	SLVS 8 ch	8
		35	SLVS – EC 2 Lane	
		24	SLVS 8 ch	10
		28	SLVS – EC 2 Lane	
		21	SLVS 8 ch	12
		24	SLVS – EC 2 Lane	
Vertical / Horizontal 1/2 subsampling	2660 (H) × 2300 (V) approx. 6.11 M pixels	101	SLVS 8 ch	8
		133	SLVS – EC 2 Lane	
		81	SLVS 8 ch	10
		108	SLVS – EC 2 Lane	
		80	SLVS 8 ch	12
		91	SLVS – EC 2 Lane	
2 × 2 FD binning mode	2660 (H) × 2300 (V) approx. 6.11 M pixels	101	SLVS 8 ch	8
		133	SLVS – EC 2 Lane	
		81	SLVS 8 ch	10
		108	SLVS – EC 2 Lane	
		80	SLVS 8 ch	12
		91	SLVS – EC 2 Lane	

## [Product Information]

Ver.1.2

# IMX540-AAQJ

Diagonal 19.3 mm (Type 1.2) CMOS solid-state Image Sensor with Square Pixel for Color Cameras

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### Description

The IMX540-AAQJ is a diagonal 19.3 mm (Type 1.2) CMOS active pixel type solid-state image sensor with a square pixel array and 24.55 M effective pixels. This chip features a global shutter with variable charge-integration time. This chip operates with analog 3.3 V, 2.9 V, digital 1.1 V, and interface 1.8 V quadruple power supply. High sensitivity and low dark current characteristics are achieved.

(Applications: FA cameras, ITS cameras)

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### Features

- ◆ CMOS active pixel type dots
- ◆ Built-in timing adjustment circuit, H/V driver and serial communication circuit
- ◆ Global shutter function
- ◆ Input frequency 37.125 MHz / 74.25 MHz / 54 MHz
- ◆ Number of recommended recording pixels: 5320 (H) × 4600 (V) approx. 24.47 M pixels
- ◆ Readout mode
  - All-pixel scan mode
  - Vertical / Horizontal 1/2 Subsampling mode
  - ROI mode
  - Vertical / Horizontal - Normal / Inverted readout mode
- ◆ Readout rate
  - Maximum frame rate in
  - All-pixel scan mode: 8 bit 35 frame/s, 10 bit 28 frame/s, 12 bit 24 frame/s
- ◆ Pulse Output Function
  - The monitor output for Exposure period
  - Programmable pulse output
- ◆ 8-bit / 10-bit / 12-bit A/D converter
- ◆ CDS / PGA function
  - 0 dB to 24 dB: Analog Gain (0.1 dB step)
  - 24.1 dB to 48 dB: Analog Gain: 24 dB + Digital Gain: 0.1 dB to 24 dB (0.1 dB step)
- ◆ I/O interface
  - SLVS (2 ch / 4 ch / 8 ch switching) output (594 / 297 / 891 / 445.5 Mbps per ch)
  - SLVS - EC (1 Lane / 2 Lane) output (4.752 / 2.376 / 1.188 Gbps per Lane)
- ◆ Recommended lens F number: 2.8 or more (Close side)

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		35	SLVS – EC 2 Lane	
		24	SLVS 8 ch	10
		28	SLVS – EC 2 Lane	
		21	SLVS 8 ch	12
		24	SLVS – EC 2 Lane	
Vertical / Horizontal 1/2 subsampling	2660 (H) × 2300 (V) approx. 6.11 M pixels	101	SLVS 8 ch	8
		106	SLVS – EC 2 Lane	
		81	SLVS 8 ch	10
		102	SLVS – EC 2 Lane	
		74	SLVS 8 ch	12
		74	SLVS – EC 2 Lane	